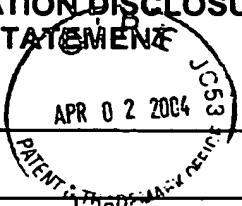


| INFORMATION DISCLOSURE STATEMENT | | Atty Docket: Serial No.: Applicant: Filing Date: Group: | | 59921 10/803,467 CHAI ET AL. MARCH 18, 2004 | | | |
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| EXAMINER: <i>[Signature]</i> | | | | DATE CONSIDERED: 8/31/05 | | | |

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

**INFORMATION DISCLOSURE
STATEMENT**

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10/803,467
CHAI ET AL.
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| | BK | | | | | | |

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

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| | BM | |
| | BN | |

EXAMINER:

R. M. H.

DATE CONSIDERED:

8/31/05

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